

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Darrell Rinerson et al.

Attorney Docket No.: UNTYP019

Application No.: 10/604,606

Examiner: WHITEHEAD JR, CARL W

Filed: August 4, 2003

Group: 2813

Title: MULTI-RESISTIVE STATE MATERIAL
THAT USES DOPANTS

Confirmation No.: 1605

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first-class mail on January 7, 2004 in an envelope addressed to the Commissioner for Patents, P.O. Box 1450 Alexandria, VA 22313-1450

Signed: _____

Laura M. Dean

**INFORMATION DISCLOSURE STATEMENT
37 CFR §§1.56 AND 1.97(b)**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

The references listed in the attached PTO Form 1449, copies of which are enclosed**, may be material to examination of the above-identified patent application. Applicants submit these references in compliance with their duty of disclosure pursuant to 37 CFR §§1.56 and 1.97. The Examiner is requested to make these references of official record in this application.

This Information Disclosure Statement is not to be construed as a representation that a search has been made, that additional information material to the examination of this application does not exist, or that these references indeed constitute prior art.

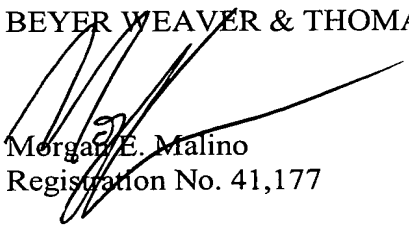
This Information Disclosure Statement is: (i) filed within three (3) months of the filing date of the above-referenced application, (ii) believed to be filed before the mailing date of a first Office Action on the merits, or (iii) believed to be filed before the mailing of a first Office Action after the filing of a Request for Continued Examination under §1.114. Accordingly, it is believed that no fees are due in connection with the filing of this Information Disclosure

** Copies of U.S. Patents and U.S. Published Applications are not enclosed.

Statement. However, if it is determined that any fees are due, the Commissioner is hereby authorized to charge such fees to Deposit Account 500388 (Order No. UNTYP019).

Respectfully submitted,

BEYER WEAVER & THOMAS, LLP



Morgan E. Malino
Registration No. 41,177

P.O. Box 778
Berkeley, CA 94704-0778
(650) 961-8300



Form 1449 (Modified) Information Disclosure Statement By Applicant (Use Several Sheets if Necessary)	Atty Docket No. UNTYP019	Application No.: 10/604,606
	Applicant: Rinerson et al. Filing Date August 4, 2003	Group 2813

U.S. Patent Documents

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub-class	Filing Date
	A	6,204,139	2001-03-20	Liu et al.			

Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
	B	Basun, S. A. et al., "Photoinduced Phenomena in $Sr_{1-x}CA_xTiO_2$, $0 \leq x \leq 0.12$ ", Ferroelectrics, Vol. 183, 1996,255-264.
	C	Beck, A. et al., "Reproducible switching effect in thin oxide films for memory applications", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000,139-141.
	D	Gerstner E.G. et al., "Nonvolatile memory effects in nitrogen doped tetrahedral amorphous carbon thin films, Journal of Applied Physics, Vol. 84, No. 10, 15 November 1998, 5647-5651.
	E	Koidl, P. et al., "Photochromism in Ni-doped $SrTiO_3$ ", Physical Review B, Vol. 14, No. 7, 1 October 1976, 2703-2708.
	F	Rossel, C. et al., "Electrical current distribution across a metal-insulator-metal structure during bistable switching", Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.
	G	Watanabe, Y. et al., "Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped $SrTiO_3$ single crystals", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.
Examiner		Date Considered

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.